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PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM 10038343	FILING DATE 01/02/2002	CLASS 382	SUBCLASS 624	GAU 2623	EXAMINER Le,Dung
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438 2818

**CONTINUING DATA VERIFIED:

THIS APPLICATION IS A DIV OF 09/524,766 03/14/2000

** FOREIGN APPLICATIONS VERIFIED:

PG-PUB	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>	
Foreign priority claimed 35 USC 119 conditions met	<input type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> yes <input type="checkbox"/> no	ATTORNEY DOCKET NO 042390P8125D	
Verified and Acknowledged Examiners's initials			
TITLE : Method for making a semiconductor device having a low-k dielectric layer			
U.S.DEP'T. OF COMM./PAT. & TM-PTO-436L(Rev. 12-94)			

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NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED	
		Assistant Examiner	Total Claims Print Claim for O.G.
ISSUE FEE		Primary Examiner	DRAWING Sheets Drwg. Figs.Drwg. Print Fig.
Amount Due	Date Paid	PREPARED FOR ISSUE	Application Examiner
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